



74V1T14

## SINGLE SCHMITT INVERTER

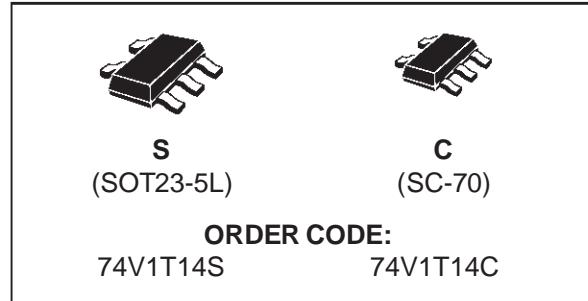
- HIGH SPEED:  $t_{PD} = 4.7 \text{ ns}$  (TYP.) at  $V_{CC} = 5\text{V}$
- LOW POWER DISSIPATION:  
 $I_{CC} = 1 \mu\text{A}$  (MAX.) at  $T_A = 25^\circ\text{C}$
- TYPICAL HYSTERESIS:  $V_h = 0.7\text{V}$  AT  $V_{CC} = 4.5\text{V}$
- POWER DOWN PROTECTION ON INPUT
- SYMMETRICAL OUTPUT IMPEDANCE:  
 $|I_{OH}| = |I_{OL}| = 8 \text{ mA}$  (MIN)
- BALANCED PROPAGATION DELAYS:  
 $t_{PLH} \approx t_{PHL}$
- OPERATING VOLTAGE RANGE:  
 $V_{CC}$  (OPR) = 4.5V to 5.5V
- IMPROVED LATCH-UP IMMUNITY

### DESCRIPTION

The 74V1T14 is an advanced high-speed CMOS SINGLE SCHMITT INVERTER fabricated with sub-micron silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology.

The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output.

Power down protection is provided on input and 0 to 7V can be accepted on input with no regard to the supply voltage. This device can be used to

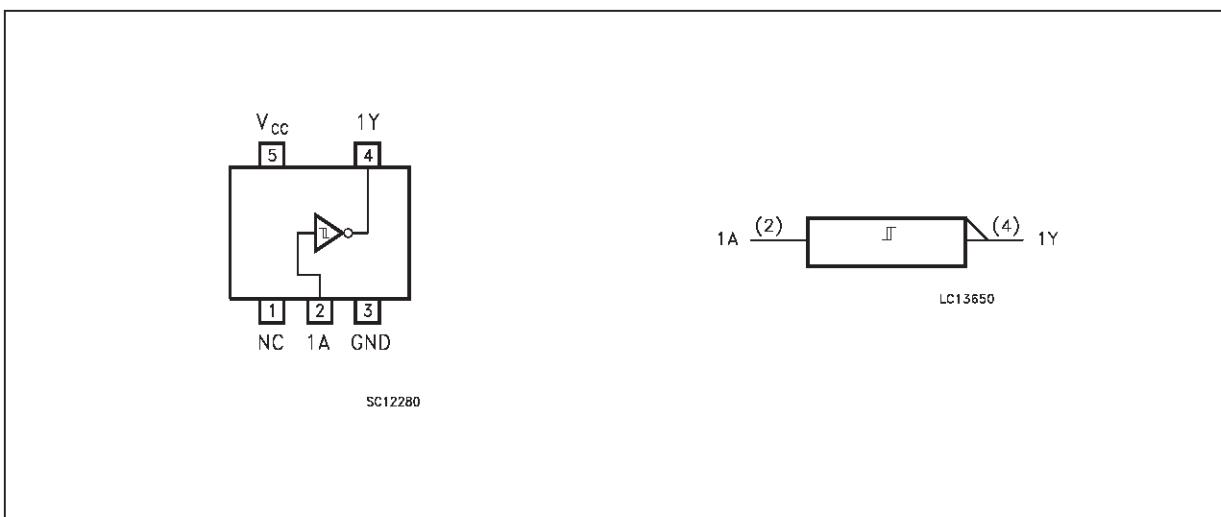


interface 5V to 3V.

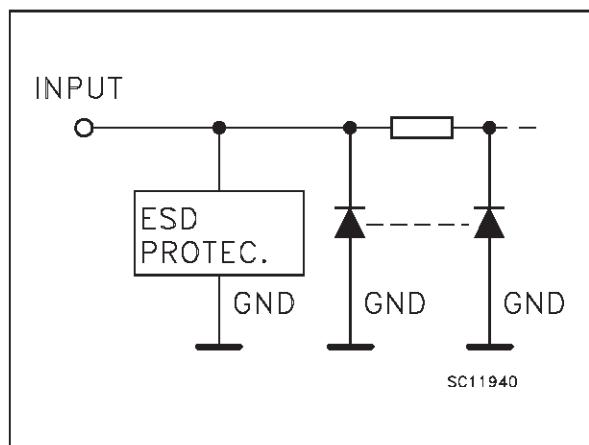
Pin configuration and function are the same as those of the V1G04 but the V1G14 has hysteresis.

The schmitt trigger function allows it to be used on line receivers with slow rise/fall input signals.

### PIN CONNECTION AND IEC LOGIC SYMBOLS



## INPUT EQUIVALENT CIRCUIT



## PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1	N.C.	Not Connected
2	1A	Data Input
4	1Y	Data Output
3	GND	Ground (0V)
5	V <sub>cc</sub>	Positive Supply Voltage

## TRUTH TABLE

A	Y
L	H
H	L

## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply Voltage	-0.5 to +7.0	V
V <sub>I</sub>	DC Input Voltage	-0.5 to +7.0	V
V <sub>O</sub>	DC Output Voltage	-0.5 to V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	DC Input Diode Current	- 20	mA
I <sub>OK</sub>	DC Output Diode Current	± 20	mA
I <sub>O</sub>	DC Output Current	± 25	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC V <sub>CC</sub> or Ground Current	± 50	mA
T <sub>stg</sub>	Storage Temperature	-65 to +150	°C
T <sub>L</sub>	Lead Temperature (10 sec)	260	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply Voltage	4.5 to 5.5	V
V <sub>I</sub>	Input Voltage	0 to 5.5	V
V <sub>O</sub>	Output Voltage	0 to V <sub>CC</sub>	V
T <sub>op</sub>	Operating Temperature	-40 to +85	°C

## DC SPECIFICATIONS

Symbol	Parameter	Test Conditions		Value					Unit	
		V <sub>CC</sub> (V)		T <sub>A</sub> = 25 °C			-40 to 85 °C			
				Min.	Typ.	Max.	Min.	Max.		
V <sub>T+</sub>	High Level Input Voltage	4.5		2.0			2.0		V	
		5.5		2.0			2.0			
V <sub>T-</sub>	Low Level Input Voltage	4.5				0.6		0.6	V	
		5.5				0.6		0.6		
V <sub>H</sub>	Hysteresis Voltage	4.5		0.4		1.4	0.4	1.4	V	
		5.5		0.4		1.5	0.4	1.5		
V <sub>OH</sub>	High Level Output Voltage	4.5	I <sub>O</sub> =-50 μA	4.4	4.5		4.4		V	
		4.5	I <sub>O</sub> =-8 mA	3.94			3.8			
V <sub>OL</sub>	Low Level Output Voltage	4.5	I <sub>O</sub> =50 μA		0.0	0.1		0.1	V	
		4.5	I <sub>O</sub> =8 mA			0.36		0.44		
I <sub>I</sub>	Input Leakage Current	0 to 5.5	V <sub>I</sub> = 5.5V or GND			±0.1		±1.0	μA	
I <sub>CC</sub>	Quiescent Supply Current	5.5	V <sub>I</sub> = V <sub>CC</sub> or GND			1		10	μA	
ΔI <sub>CC</sub>	Additional Worst Case Supply Current	5.5	One Input at 3.4V, other input at V <sub>CC</sub> or GND			1.35		1.5	mA	

AC ELECTRICAL CHARACTERISTICS (Input t<sub>r</sub> = t<sub>f</sub> = 3 ns)

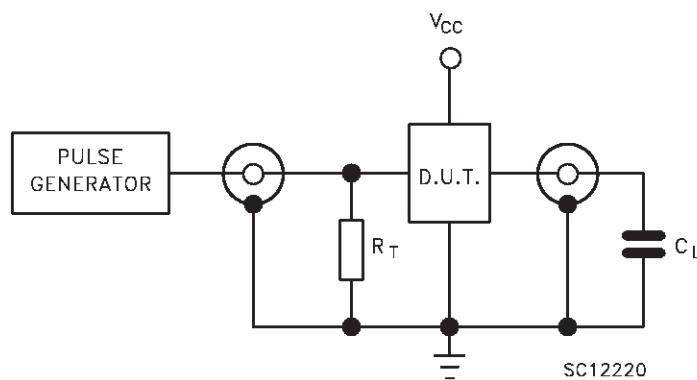
Symbol	Parameter	Test Condition			Value					Unit	
		V <sub>CC</sub> (*) (V)	CL (pF)		T <sub>A</sub> = 25 °C			-40 to 85 °C			
					Min.	Typ.	Max.	Min.	Max.		
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Time	5.0	15			5.0	7.5	1.0	9.0	ns	
		5.0	50			6.5	8.5	1.0	10.0		

(\*) Voltage range is 5V ± 0.5V

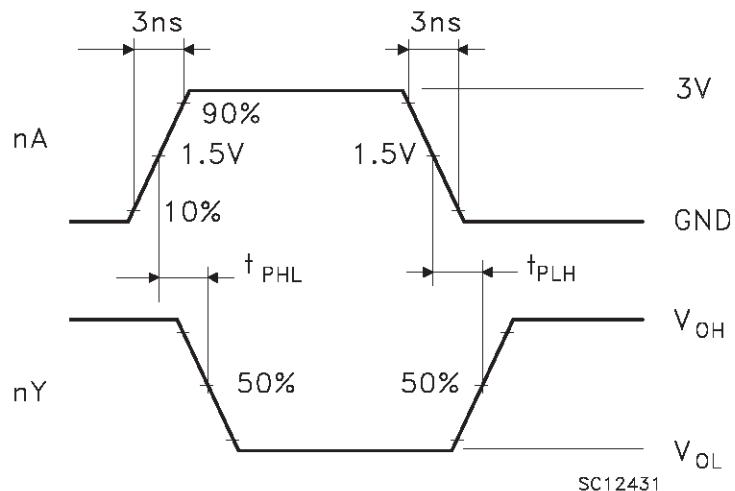
## CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions			Value					Unit	
		V <sub>CC</sub> (*) (V)	CL (pF)		T <sub>A</sub> = 25 °C			-40 to 85 °C			
					Min.	Typ.	Max.	Min.	Max.		
C <sub>IN</sub>	Input Capacitance					4	10		10	pF	
C <sub>PD</sub>	Power Dissipation Capacitance (note 1)					12				pF	

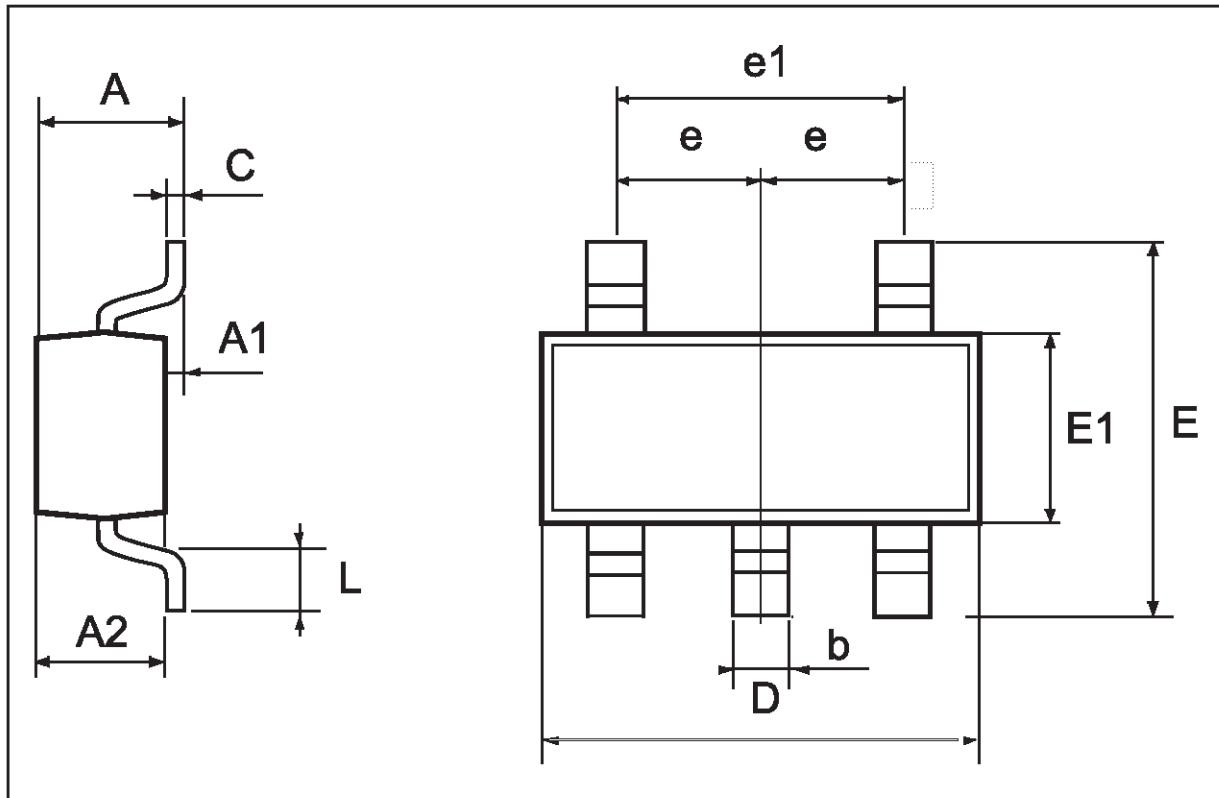
1) C<sub>PD</sub> is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. I<sub>CC(OPT)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>IN</sub> + I<sub>CC</sub>

**TEST CIRCUIT**

$C_L = 15/50 \text{ pF}$  or equivalent (includes jig and probe capacitance)  
 $R_T = Z_{\text{out}}$  of pulse generator (typically  $50\Omega$ )

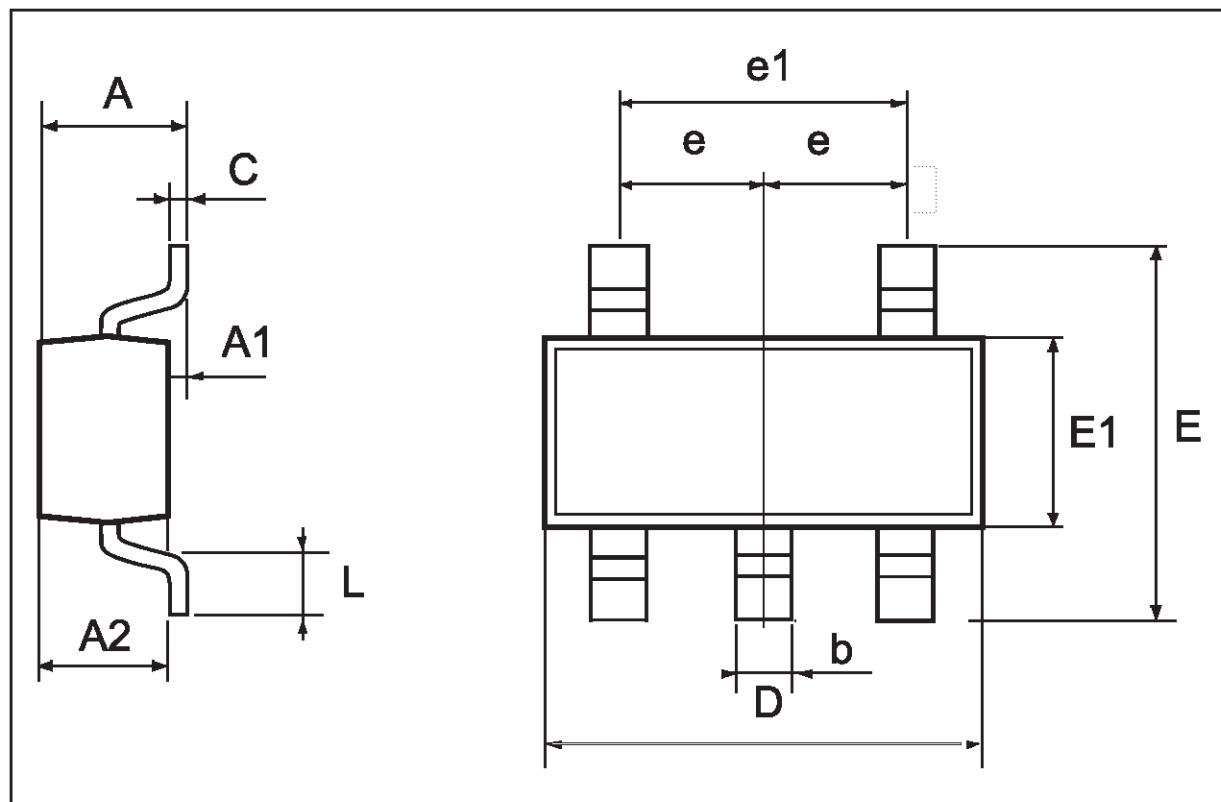
**WAVEFORM: PROPAGATION DELAYS (f=1MHz; 50% duty cycle)**

SOT23-5L MECHANICAL DATA						
DIM.	mm			mils		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	0.90		1.45	35.4		57.1
A1	0.00		0.15	0.0		5.9
A2	0.90		1.30	35.4		51.2
b	0.35		0.50	13.7		19.7
C	0.09		0.20	3.5		7.8
D	2.80		3.00	110.2		118.1
E	2.60		3.00	102.3		118.1
E1	1.50		1.75	59.0		68.8
L	0.35		0.55	13.7		21.6
e		0.95			37.4	
e1		1.9			74.8	



## SC-70 MECHANICAL DATA

DIM.	mm			mils		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	0.80		1.10	31.5		43.3
A1	0.00		0.10	0.0		3.9
A2	0.80		1.00	31.5		39.4
b	0.15		0.30	5.9		11.8
C	0.10		0.18	3.9		7.1
D	1.80		2.20	70.9		86.6
E	1.80		2.40	70.9		94.5
E1	1.15		1.35	45.3		53.1
L	0.10		0.30	3.9		11.8
e		0.65			25.6	
e1		1.3			51.2	



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